Notice of References Cited

Application/Control No. 10/580,560	Reexamination	Applicant(s)/Patent Under Reexamination KUDO ET AL.		
Examiner	Art Unit			
Xinning(Tom) Niu	2828	Page 1 of 1		

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	Α	US-2003/0021319	01-2003	Aoki, Masahiro	372/46
*	В	US-4,740,987	04-1988	McCall et al.	372/96
*	С	US-5,610,930	03-1997	Macomber et al.	372/36
*	D	US-5,091,916	02-1992	Cimini et al.	372/96
	Е	US-			
	F	US-			,
	G	US-			
	Н	US-			
	ı	US-			
	J	US-			
	К	US-			
	L	US-			
	М	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N			•		
	0					
	Р			•		
	Q					
	R				,	
	s					
	Т					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
*	U	Itaya et al. "Low Threshold Current GalnAsP/InP DFB Laser," IEEE J. Quantum Electron, Vol. QE-23, NO. 6, June 1987, pp. 828-834.
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.